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| APPLICATION NO. | FILING DATE                          | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO.   | CONFIRMATION NO. |  |
|-----------------|--------------------------------------|----------------------|-----------------------|------------------|--|
| 10/608,081      | 06/30/2003                           | Kye Nam Lee          | 40296-0024            | 7874             |  |
| 26633           | 7590 03/07/2005                      |                      | EXAM                  | EXAMINER         |  |
|                 | HELLER EHRMAN WHITE & MCAULIFFE LLP  |                      |                       | VINH, LAN        |  |
|                 | SISLAND AVE, NW<br>ON, DC 20036-3001 |                      | ART UNIT PAPER NUMBER |                  |  |
| WASIMIOI        | 514, DC 20030-3001                   |                      | 1765                  |                  |  |

DATE MAILED: 03/07/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

|  |  |   | 111         |
|--|--|---|-------------|
|  | Application No.  | Applicant(s)  |             |
| Office A 4' O  | 10/608,081   | LEE ET AL.  | ,           |
| Office Action Summary  | Examiner   | Art Unit  | <u> </u>    |
|  | Lan Vinh   | 1765  |             |
| The MAILING DATE of this communication appeared for Reply  | pears on the cover sheet with  | the correspondence address  |             |
| A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b). | 36(a). In no event, however, may a rep<br>y within the statutory minimum of thirty<br>will apply and will expire SIX (6) MONTI<br>e, cause the application to become ABA | ly be timely filed (30) days will be considered timely. HS from the mailing date of this communication. NDONED (35 U.S.C. § 133). | (           |
| Status   |  |   |             |
| 1) Responsive to communication(s) filed on 30 J  | une 2003.  |   |             |
| ,  | action is non-final.   |   |             |
| 3)☐ Since this application is in condition for allowa  |  | s, prosecution as to the merits is  |             |
| closed in accordance with the practice under E   | Ex parte Quayle, 1935 C.D.   | 11, 453 O.G. 213.   |             |
| Disposition of Claims  |  |   |             |
| 4)  Claim(s) 1-3 is/are pending in the application. 4a) Of the above claim(s) is/are withdra 5)  Claim(s) is/are allowed. 6)  Claim(s) 1-3 is/are rejected. 7)  Claim(s) is/are objected to. 8)  Claim(s) are subject to restriction and/o   |  |   |             |
| Application Papers   |  |   |             |
| 9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) accomplicant may not request that any objection to the   | epted or b)□ objected to by  |   |             |
| Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex  | · · · · · · · · · · · · · · · · · · ·  | •   | <b>).</b> , |
| Priority under 35 U.S.C. § 119   |  |   |             |
| 12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list   | s have been received.<br>s have been received in Apprity documents have been re<br>u (PCT Rule 17.2(a)).   | olication No. <u>10/608,081</u> .<br>eceived in this National Stage   |             |
| Attachment(s)  |  |   |             |
| <ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)<br/>Paper No(s)/Mail Date</li> </ol>  |  | Mail Date<br>nrmal Patent Application (PTO-152)   | اگان        |

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#### **DETAILED ACTION**

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### Claim Objections

1. Claim 1 is objected to because of the following informalities: In line 11 of claim 1, "photolithogrphy" appears to be a typographical error. The examiner suggests replacing "photolithogrphy" with --photolithography--. Appropriate correction is required.

## Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claim 1 is rejected under 35 U.S.C. 102(e) as being anticipated by Durlam et al (US 6,365,419)

Durlam discloses a method for fabricating an MRAM cell comprising the steps of: forming a metal layer 42 connected to a semiconductor substrate through a lower dielectric/ insulating layer 47 (col 4, lines 20-26; fig. 7)

sequentially forming a pinned magnetic layer 44, a tunnel barrier layer 45 and free magnetic layer 46 on the metal layer 42 (col 4, lines 26-30)

forming a hard mask layer 48 on the magnetic layer 46 (col 4, lines 30-31)

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the hard mask layer 48 and the free magnetic layer 46 are patterned using an etching step and MTJ cell mask 40 as seen in fig. 7, the tunnel barrier layer is exposed after the patterning step

sequentially forming a barrier layer 52 and insulating layer 50 on the entire surface (col 4, lines 35-45)

forming an insulating spacer on the sidewall of the hard mask 48 and magnetic layer 46 by using any well known processes for the formation of sidewalls (col 4, lines 36-42; fig. 9), which reads on anisotropically etching the insulating film to form the spacer on the sidewall since it is well known in the art to anisotropically etching the insulating film to form sidewall spacers (see prior art of record for evidence of this basis) etching the tunnel layer 45, the pinned magnetic layer 44 and metal layer 42 using the insulating spacer and the hard mask layer as a mask to define/form MTJ cell and a connection layer (col 4, lines 60-67)

# Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 2-3 rejected under 35 U.S.C. 103(a) as being unpatentable over Durlam et al (US 6,365,419) in view of Parkin et al (US 6,518,588)

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Durlam's method has been described above. Unlike the instant claimed inventions as per claims 2-3, Durlam fails to disclose forming a Ta barrier layer and an insulating oxide film

Parkin discloses a method for forming a MRAM comprises the steps forming a TaN barrier layer and a insulating oxide film (col 3, lines 34-35, col 6, lines 9-10)

Since both Durlam and Parkin are directed to method of forming MRAM one skilled in the art at the time the invention was made would have found it obvious to modify Durlam by using an insulating oxide film as per Parkin because Parkin discloses that the studs/connections of a MRAM are formed in vias in the surrounding silicon dioxide insulating material (col 3, lines 26-35). One skilled in the art at the time the invention was made would also have found it obvious to modify Durlam by forming a barrier layer of Ta in view of Parkins teaching because Parkin discloses that TaN which acts as a thermal diffusion barrier are also useful for magnetic tunnel junction device (col 6, lines 66-67)

6. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Sato (US 6,608,347) discloses the step of anisotropically etch an insulating film to form sidewall spacers (col 8, lines 33-36)

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#### Conclusion

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Lan Vinh whose telephone number is 571 272 1471. The examiner can normally be reached on M-F 8:30-5:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on 571 272 1465. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

March 2, 2005